TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

2SJ167

1

High Speed Switching Applications Analog Switch Applications Interface Applications

- Excellent switching time: ton = 14 ns (typ.)
- High forward transfer admittance: $|Y_{fs}| = 100 \text{ mS (min)}$
- Low on resistance: RDS (ON) = 1.3Ω (typ.)
- Enhancement-mode
- Complementary to 2SK1061

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V_{DSS}	-60	٧	
Gate-source voltage		V_{GSS}	±20	٧	
Drain current	DC	I _D	-200	mA	
	Pulse	I _{DP}	-800		
Drain power dissipation (Ta = 25°C)		P _D	300	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

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1.27

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2.56

0.75May.

NIWL 21

NIWL 21

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DRAIN
3. GATE

JEDEC

JEITA

TOSHIBA

2-4E1E

Weight: 0.13 g (typ.)

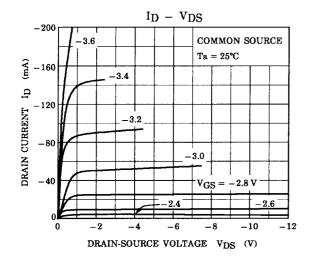


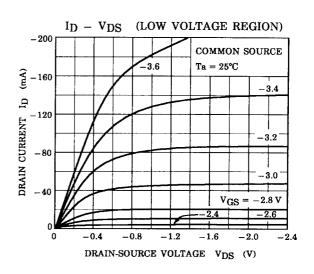
Electrical Characteristics (Ta = 25°C)

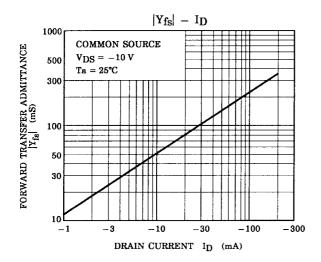
Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curre	ent	I _{GSS}	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$	_	_	±100	nA
Drain cut-off curre	nt	I _{DSS}	$V_{DS} = -60 \text{ V}, V_{GS} = 0$	_	_	-10	μА
Drain-source brea	kdown voltage	V (BR) DSS	$I_D = -1 \text{ mA}, V_{GS} = 0$	-60	_	_	V
Gate threshold vol	tage	V _{th}	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	-2	_	-3.5	V
Forward transfer a	dmittance	Y _{fs}	$V_{DS} = -10 \text{ V}, I_D = -50 \text{ mA}$	100	_	_	mS
Drain-source ON r	esistance	R _{DS} (ON)	$I_D = -50 \text{ mA}, V_{GS} = -10 \text{ V}$	_	1.3	2.0	Ω
Drain-source ON v	/oltage	V _{DS} (ON)	$I_D = -50 \text{ mA}, V_{GS} = -10 \text{ V}$	_	-65	-100	mV
Input capacitance		C _{iss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	73	85	pF
Reverse transfer of	apacitance	C _{rss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	15	22	pF
Output capacitance		C _{oss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	48	60	pF
Switching time	Rise time	t _r	$ \begin{array}{c c} & I_{D} = -100 \text{ mA} \\ \hline & I_{D} = $	_	8	_	ns
	Turn-on time	t _{on}		_	14		
	Fall time	t _f	$V_{DD} \stackrel{\text{i.o.m.}}{=} -30 \text{V}$		35		
	Turn-off time	t _{off}	V_{IN} : t_r , t_f < 5 ns D.U. \leq 1% (Z_{out} = 50 Ω)	_	100	_	

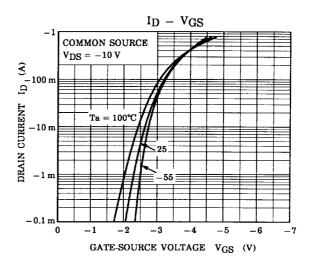
Note: This transistor is the electrostatic sensitive device.

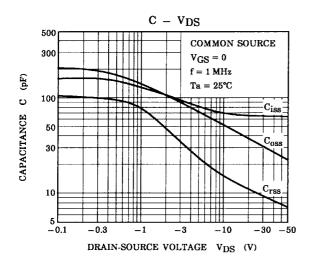
Please handle with caution.



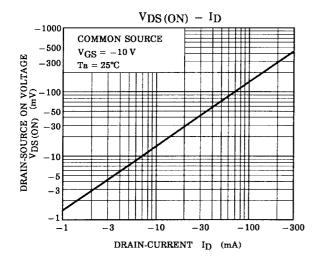


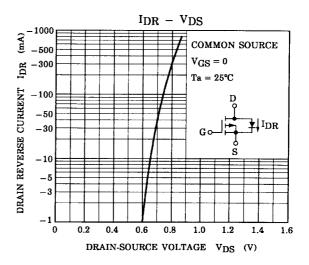


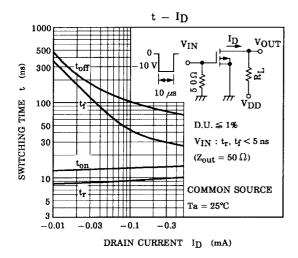


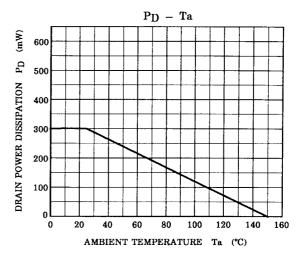


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4

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5

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